

BTA308X-800C0

3Q Hi-Com Triac Rev.04 - 27 December 2022

Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a TO220F "full pack" plastic package. This triac is intended for use in motor control circuits where high blocking voltage, high static and dynamic dV/dt as well as high dlcom/dt can occur. This "series C0" triac will commutate the full rated RMS current at the maximum rated junction temperature without the aid of a snubber.

2. Features and benefits

- 3Q technology for improved noise immunity
- · High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- Isolated mounting base package
- Optimized for highest noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only
- High voltage capability

3. Applications

- Compressor starting controls circuits
- General purpose motor controls
- · Reversing induction motor control e.g. vertical axis washing machines

4. Quick reference data

Table 1. Q	uick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Absolute	maximum rating					
V_{DRM}	repetitive peak off-state voltage		-	-	800	V
$I_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	full sine wave; T _h ≤ 100 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	60	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	-	65	А
Tj	junction temperature		-	-	150	°C
Static ch	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	5	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	5	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	5	-	35	mA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
V _T	on-state voltage	I _τ = 10 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.65	V
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150°C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	1500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit; Fig. 12}$	12	-	-	A/ms
		$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit; Fig. 12}$	7	-	-	A/ms

5. Pinning information

Table 2. F	<u>Pinning infor</u>	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	NI
2	T2	main terminal 2		T2-T1
3	G	gate		G sym051
mb	n.c.	mounting base; isolated		

6. Ordering information

Table 3. Ordering information								
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
BTA308X-800C0	TO220F	BTA308X-800C0Q	Tube	50	SOT186A	14-Nov-2013		
BTA308X-800C0/L02	TO220F	BTA308X-800C0/L02Q	Tube	50	SOT186A/L02	14-Nov-2013		
BTA308X-800C0/L03	TO220F	BTA308X-800C0/L03Q	Tube	50	SOT186A/L03	14-Nov-2013		

7. Marking

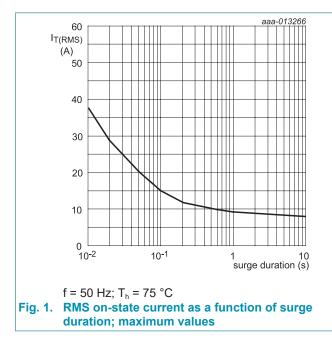
Type number	Marking codes		
	Assembly factory: d	Assembly factory: A	
BTA308X-800C0	BTA308X 800C0 PJdxxxx xx	BTA308X 800C0 PJAxxxx xx	

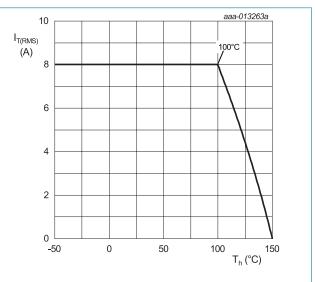
8. Limiting values

Table 5. Limiting values

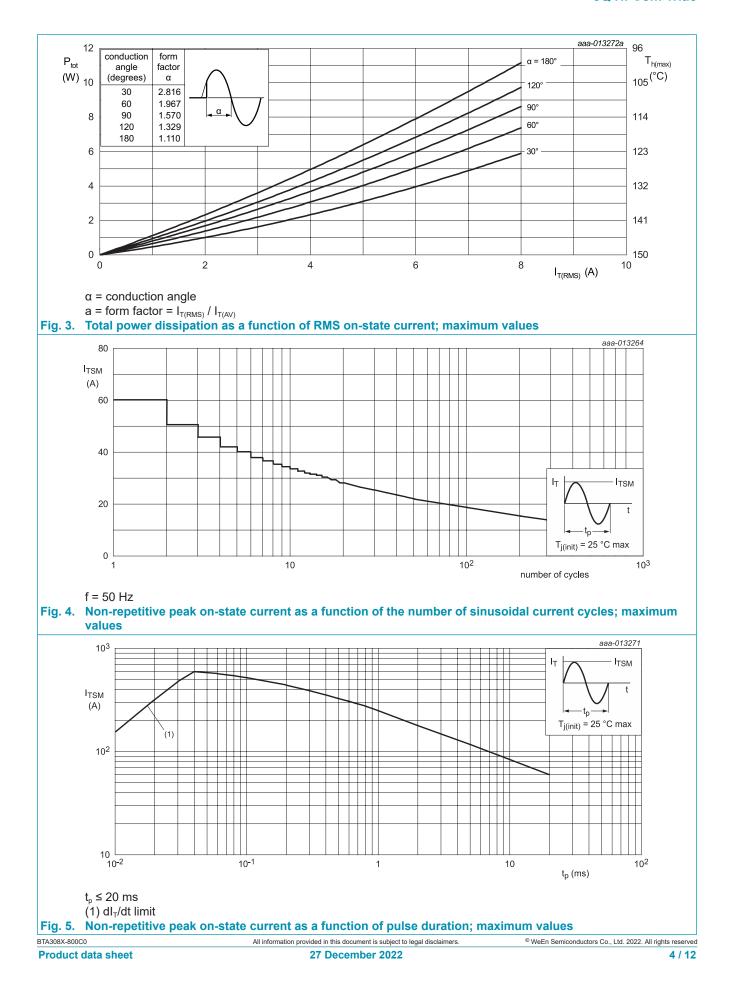
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _h ≤ 100 °C; <u>Fig 1; Fig 2; Fig 3</u>	-	8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5	-	60	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	65	А
l ² t	I ² t for fusing	t _P = 10 ms; SIN	-	18	A ² s
dl _T /dt	rate of rise of on-state current	I _G = 0.2 A	-	100	A/µs
I _{GM}	peak gate current		-	2	А
P_{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C



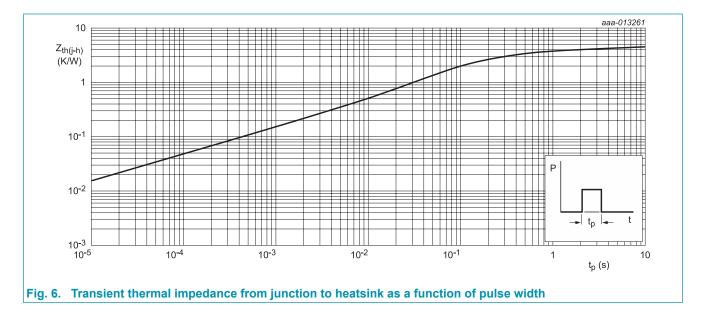






9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to	full cycle or half cycle; with heatsink compound; Fig 6	-	-	4.5	K/W
he	heatsink	full cycle or half cycle; without heatsink compound	-	-	6.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W



10. Isolation characteristics

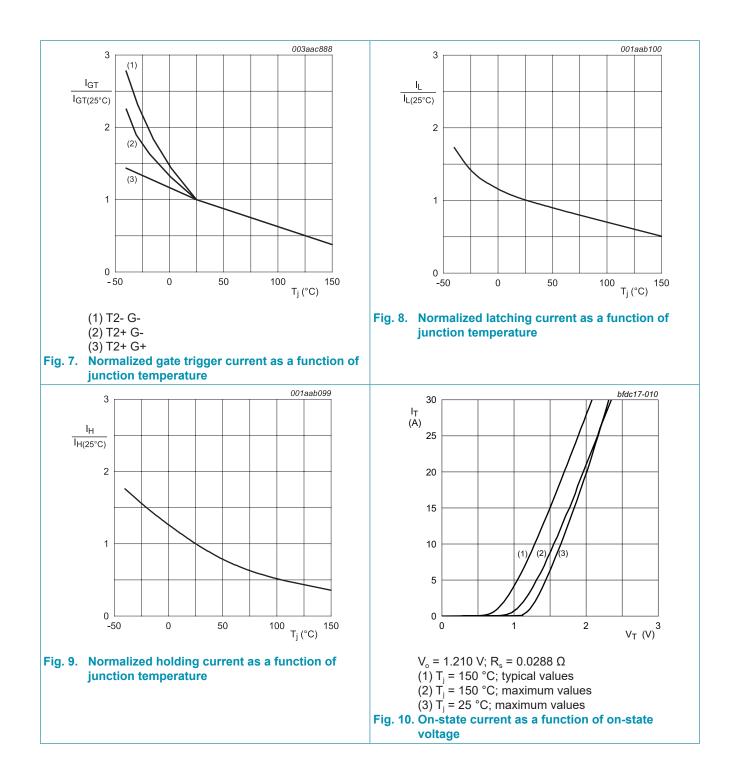
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C	-	-	2500	V
C _{isol}	isolation capacitance	from main terminal 2 to external heatsink; f = 1 MHz; $T_h = 25 \degree C$	-	10	-	pF

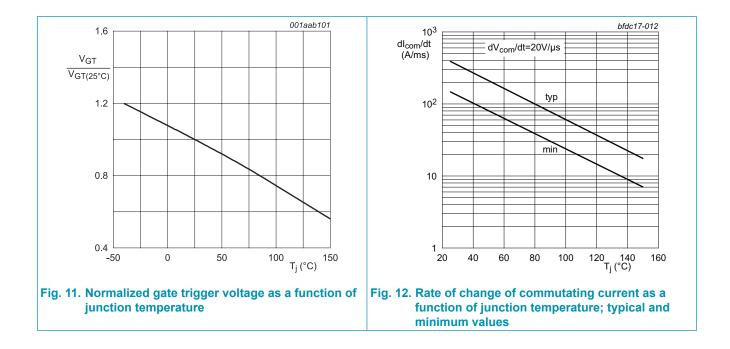
11. Characteristics

Symbol	haracteristics Parameter	Conditions	Min	Тур	Max	Unit
		Conditions		Тур	IVIAX	
Static cha	aracteristics		1			
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; <u>Fig. 7</u>	5	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	5	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	5	-	35	mA
I _L	latching current	$V_{\rm D}$ = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	50	mA
		V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	75	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	50	mA
V _T	on-state voltage	I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.65	V
V _{GT}	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C	0.2	0.45	-	V
I _D	off-state current	$V_{\rm D}$ = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _i = 125 °C	-	-	0.5	mA
Dynamic	characteristics	-	II			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	1500	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_{D} = 400 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ I}_{T(RMS)} = 8 \text{ A}; $ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit; Fig. 12}$	12	-	-	A/ms
		$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit; Fig. 12}$	7	-	-	A/ms

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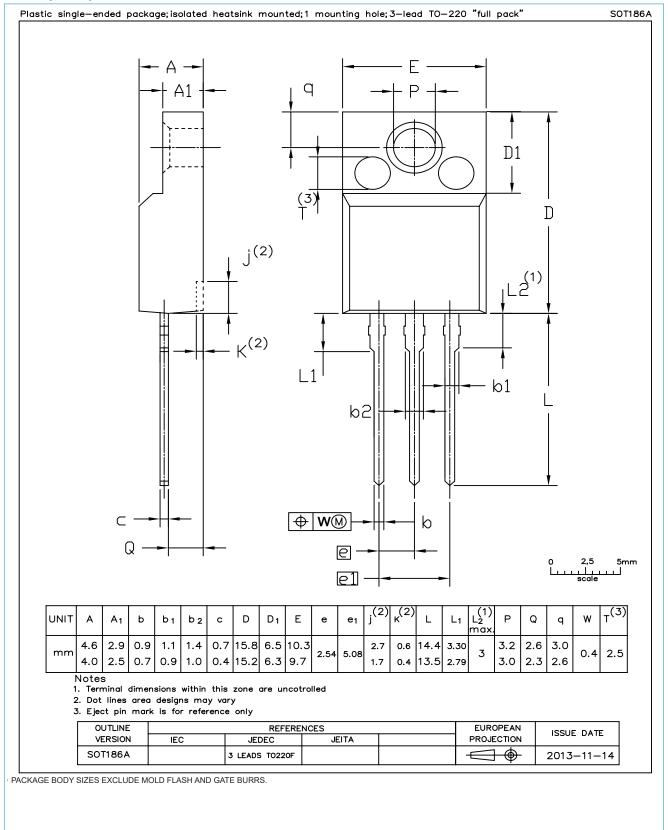
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12. Package outline

Assembly factory: d & A



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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